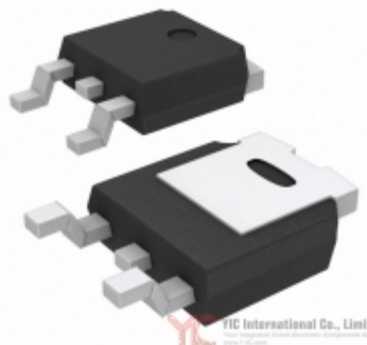



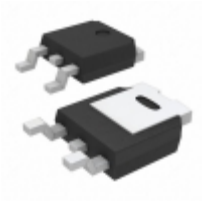






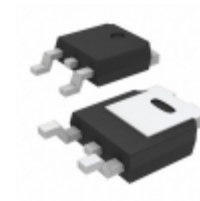
 life.augmented	Hersteller-Teilenummer: STD12N50M2
	Hersteller / Marke: STMicroelectronics
	Teil der Beschreibung: MOSFET N-CH 500V 10A DPAK
	Datenblätter:  STD12N50M2.pdf
RoHs Status: Bleifrei / RoHS-konform	Lagerzustand: New original, 2574 pcs Stock Available.
Lieferung von: Hong Kong	Versandweg: DHL/Fedex/TNT/UPS/EMS
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	STD12N50M2
Hersteller	STMicroelectronics
Beschreibung	MOSFET N-CH 500V 10A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2574 pcs Stock
Serie	MDmesh™ M2
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	85W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	10A (Tc)
Rds On (Max) @ Id, Vgs	380 mOhm @ 5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	550pF @ 100V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)
















STD12N50M2 ist neu im Original, Suche STD12N50M2 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie STD12N50M2 STMicroelectronics mit Garantie und Vertrauen.
Anfrage STD12N50M2: Info@Y-IC.com

Sie können auch interessiert sein:

 STD12N65M2 STMicroelectronics MOSFET N-CH 650V 8A DPAK	 STD12N10T4G AMI Semiconductor / ON Semiconductor MOSFET N-CH SPCL 100V DPAK	 STD12N06T4 STM STD12N06T4 STM	 STD12NE06 ST STD12NE06 ST
 STD12N65M5 STMicroelectronics MOSFET N-CH 650V 8.5A DPAK	 STD12N60DM2AG STMicroelectronics AUTOMOTIVE-GRADE N-CHANNEL 600 V	 STD12N60M2 STMicroelectronics MOSFET N-CH 600V 9A DPAK	 STD12N50DM2 STMicroelectronics N-CHANNEL 500 V, 0.35 OHM TYP.,

heiße Teile

Mehr

 STD116GK14B	 STD116GK16	 STD116GK16B	 STD116GK18	 STD116GK18B
 STD11N50M2	 STD11N65M2	 STD11N65M5	 STD11NM50N	 STD11NM60N
 STD11NM60ND	 STD120N4F6	 STD120N4LF6	 STD123SF	 STD123UF
 STD125GK16	 STD12L01	 STD12L01A	 STD12N05LT4	 STD12N06
 STD12N06L	 STD12N06LT4	 STD12N06T4	 STD12N10L	 STD12N10L-TR
 STD12N60M2	 STD12N65M5	STD12NE06	STD12NE06L-TR	STD12NE06LT4
STD12NE06T4	STD12NF06-1	STD12NF06L-1	STD12NF06LT4	STD12NF06T4
STD12NM50N	STD13003	STD13003T4	STD13005F	STD13005FB
STD13005I	STD13007	STD130GK08	STD130GK08B	STD130GK12
STD130GK12B	STD130GK14	STD130GK14B	STD130GK16	STD130GK16B

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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